NSN 5961-00-871-7519

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-871-7519 **Inclosure Material:** Metal **Overall Length:** 1.215 inches **Overall Diameter:** 0.610 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 175.0 collector to base voltage, dc and 80.0 collector to emitter voltage, dc and 10.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 96214-507510 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-871-7519 Transistor - Page 2 of 2



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